


Single Phase Bridge (Power Modules), 25 A/35 A



D-34

FEATURES

- Universal, 3 way terminals: push-on, wrap around or solder
- High thermal conductivity package, electrically insulated case
- Center hole fixing
- Excellent power/volume ratio
- Nickel plated terminals solderable using lead (Pb)-free solder; solder alloy Sn/Ag/Cu (SAC305); solder temperature 260 to 275 °C
- UL E300359 approved 
- RoHS compliant
- Designed and qualified for industrial and consumer level


RoHS
COMPLIANT

PRODUCT SUMMARY

I_o	25 A/35 A
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DESCRIPTION

A range of extremely compact, encapsulated single phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and instrumentation applications.

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	26MB-A	36MB-A	UNITS
I_o		25	35	A
	T_c	70	55	°C
I_{FSM}	50 Hz	400	475	A
	60 Hz	420	500	
I^2t	50 Hz	790	1130	A ² s
	60 Hz	725	1030	
V_{RRM}	Range	1400 to 1600	1400 to 1600	V
T_J		- 55 to 150	- 55 to 150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT T_J MAXIMUM mA
26MB..A	140	1400	1500	2
36MB..A	160	1600	1700	

MB High Voltage Series



Vishay High Power Products

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FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS		26MB-A	36MB-A	UNITS	
Maximum DC output current at case temperature	I_o	Resistive or inductive load		25	35	A	
		Capacitive load		20	28		
				65	60	°C	
Maximum peak, one cycle non-repetitive forward current	I_{FSM}	t = 10 ms	No voltage reapplied	Initial $T_J = T_J$ maximum	400	475	A
		t = 8.3 ms					
		t = 10 ms	100 % V_{RRM} reapplied		335	400	
		t = 8.3 ms			350	420	
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reapplied		790	1130	A ² s
		t = 8.3 ms					
		t = 10 ms	100 % V_{RRM} reapplied		560	800	
		t = 8.3 ms			512	730	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	I^2t for time $t_x = I^2\sqrt{t} \times \sqrt{t_x}$; $0.1 \leq t_x \leq 10$ ms, $V_{RRM} = 0$ V		5.6	11.3	kA ² √s	
Low level of threshold voltage	$V_{F(TO)1}$	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, T_J maximum		0.70	0.74	V	
High level of threshold voltage	$V_{F(TO)2}$	$(I > \pi \times I_{F(AV)})$, T_J maximum		0.75	0.79		
Low level forward slope resistance	r_{t1}	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, T_J maximum		7.0	5.5	mΩ	
High level forward slope resistance	r_{t2}	$(I > \pi \times I_{F(AV)})$, T_J maximum		6.4	5.2		
Maximum forward voltage drop	V_{FM}	$T_J = 25$ °C, $I_{FM} = 40$ Apk (26MB)		$t_p = 400$ μs	1.25	1.3	V
		$T_J = 25$ °C, $I_{FM} = 55$ Apk (36MB)					
Maximum DC reverse current per diode	I_{RRM}	$T_J = 25$ °C, at V_{RRM}		10	10	μA	
RMS isolation voltage base plate	V_{ISOL}	f = 50 Hz, t = 1 s		2700	2700	V	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		26MB-A	36MB-A	UNITS
Junction and storage temperature range	T_J, T_{Stg}			- 55 to 150		°C
Maximum thermal resistance, junction to case per bridge	R_{thJC}			1.7	1.35	K/W
Maximum thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth, flat and greased		0.2		
Mounting torque ± 10 %		Bridge to heatsink		2.0		Nm
Approximate weight				20		g

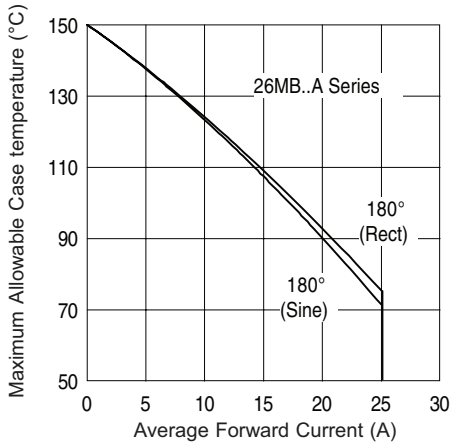


Fig. 1 - Current Ratings Characteristics

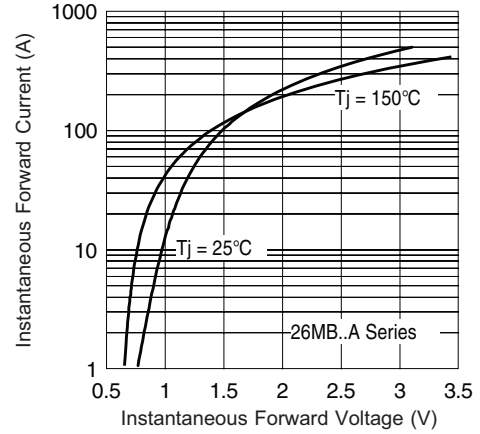


Fig. 2 - Forward Voltage Drop Characteristics

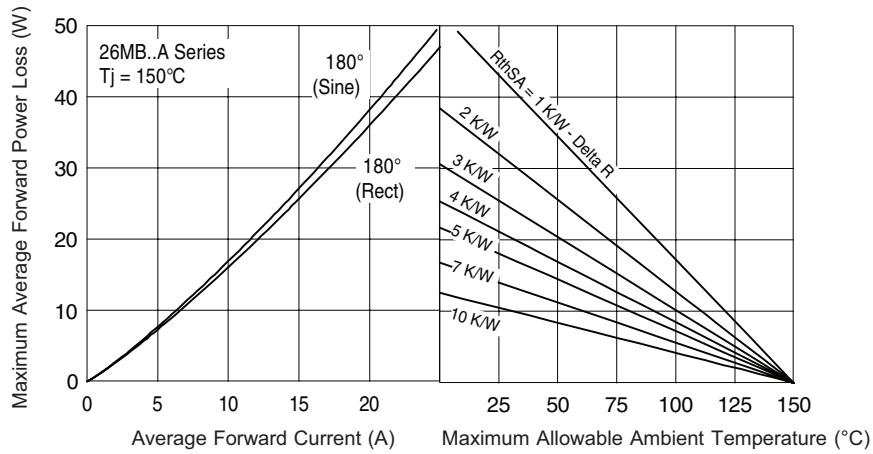


Fig. 3 - Total Power Loss Characteristics

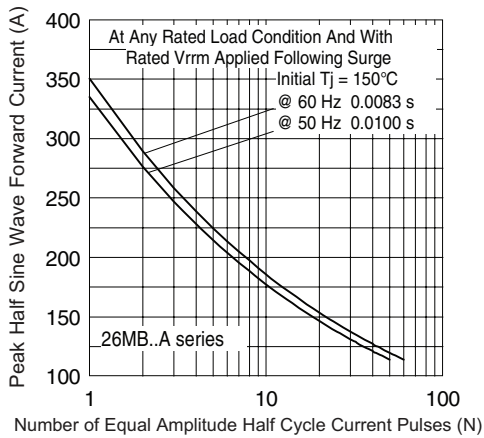


Fig. 4 - Maximum Non-Repetitive Surge Current

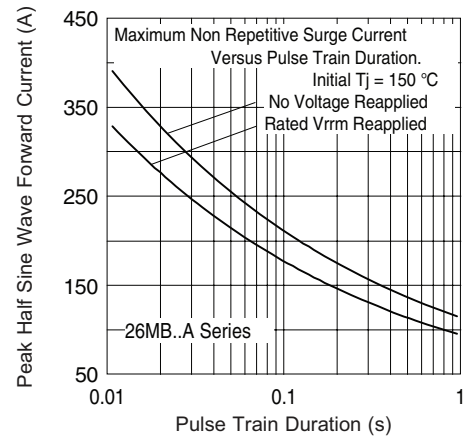


Fig. 5 - Maximum Non-Repetitive Surge Current

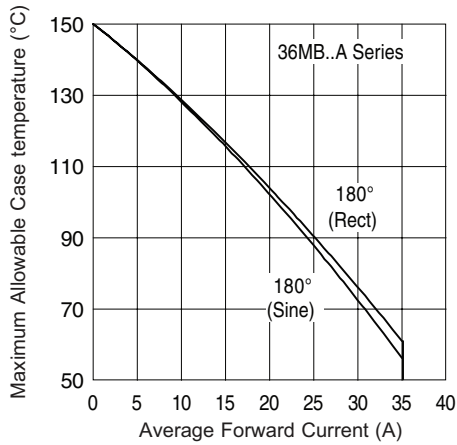


Fig. 6 - Current Ratings Characteristics

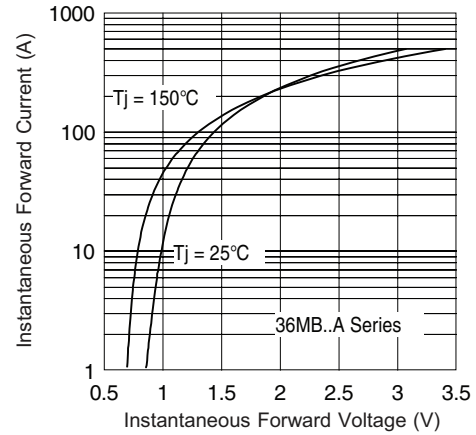


Fig. 7 - Forward Voltage Drop Characteristics

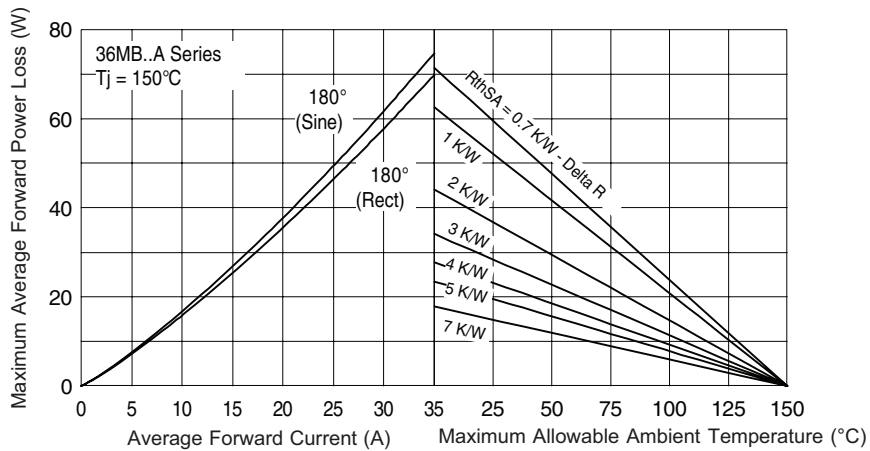


Fig. 8 - Total Power Loss Characteristics

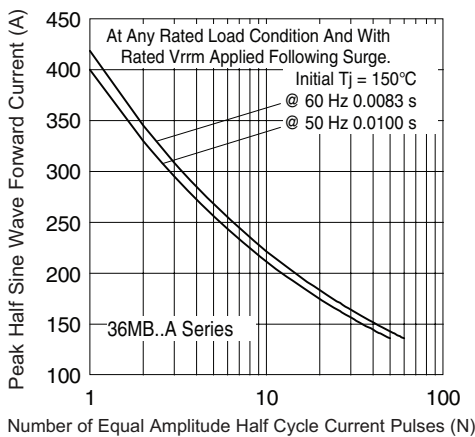


Fig. 9 - Maximum Non-Repetitive Surge Current

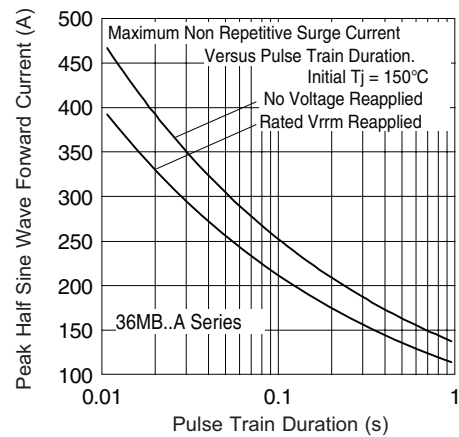
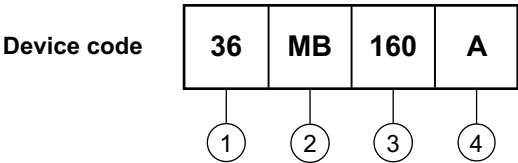


Fig. 10 - Maximum Non-Repetitive Surge Current

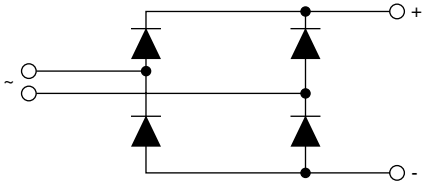
ORDERING INFORMATION TABLE



- 1** - Current rating code
- 2** - Circuit configuration:
 MB = Single phase european coding
- 3** - Voltage code x 10 = V_{RRM}
- 4** - Diode bridge rectifier:
 A = 26 MB, 36MB series

26 = 25 A (average)
 36 = 35 A (average)

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95326



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